

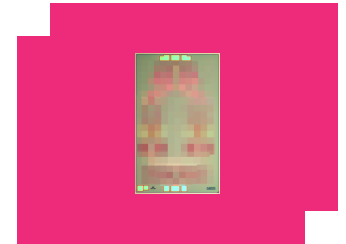
MMD-1648LCH

High Isolation GaAs MMIC Doubler

DEVICE OVERVIEW

General Description

The MMD-1648L is a balanced MMIC doubler covering 16 to 48 GHz on the output. It features superior isolations and harmonic suppressions across a broad bandwidth in a highly miniaturized form factor. Accurate, nonlinear simulation models are available for Microwave Office® through the Marki Microwave PDK. The MMD-1648L is available as a wire bondable chip or a connectorized package. The MMD-1648L is a superior alternative to Marki Microwave carrier and packaged doublers.



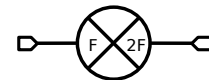
Features

- Compact Chip Style Package (0.058" x 0.096"x0.004")
- CAD Optimized for Superior Suppressions and Efficiency
- Broadband Performance
- Excellent Unit-to-Unit Repeatability
- Fully nonlinear software models available with Marki PDK for Microwave Office®
- RoHS Compliant

Applications

N/A

Functional Block Diagram



Part Ordering Options

Part Number	Description	Package	Connectors	Green Status	Product Lifecycle	Export Classification
<u>MMD-1648LS</u>	High Isolation GaAs MMIC Doubler	S	<u>Standard</u>	REACH RoHS	Released	EAR99
MMD-1648LCH	High Isolation GaAs MMIC Doubler	CH	-	REACH RoHS	Released	EAR99

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Revision History

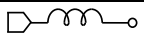

Revision Code	Revision Date	Comment
-	2016-08-01	Initial Release
A	2019-09-01	Added CH Package Dimensions
B	2020-01-01	Die Shrink

Port Configuration and Functions

Port Diagram



Port Functions

Port	Function	Description	Equivalent Circuit for Package
2F	Output	2x Input Frequency output port. The output port is DC open and AC matched to 50 Ohms from 16 to 48 GHz. Blocking capacitor is optional.	
F	Input	Input 1x Frequency Port. The input port is DC open and AC matched to 50 Ohms from 8 to 24 GHz. Blocking capacitor is optional.	

Specifications

Absolute Maximum Ratings

Parameter	Maximum Rating	Unit
Maximum Operating Temperature	100	°C
Maximum Storage Temperature	125	°C
Minimum Operating Temperature	-55	°C
Minimum Storage Temperature	-65	°C
RF Power Handling (RF+LO), 100°C	20	dBm
RF Power Handling (RF+LO), 25°C	25	dBm

Package Information

Parameter	Details	Rating
Dimensions	-	2.45 x 1.38 mm

Electrical Specifications

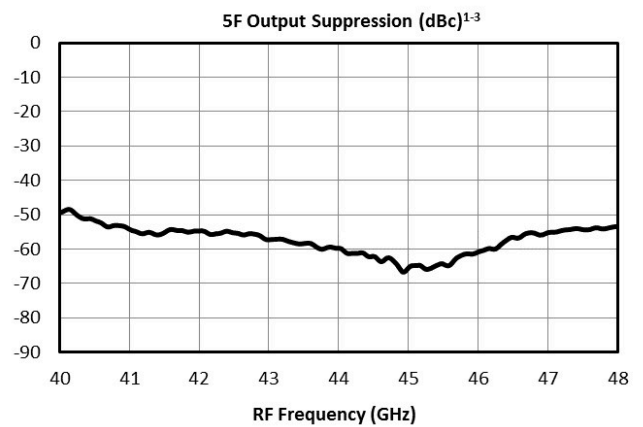
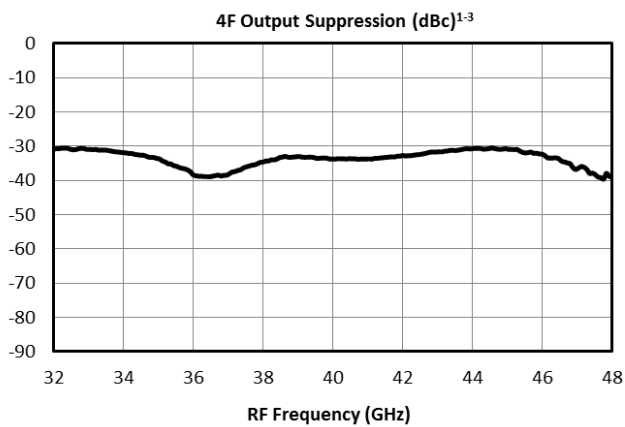
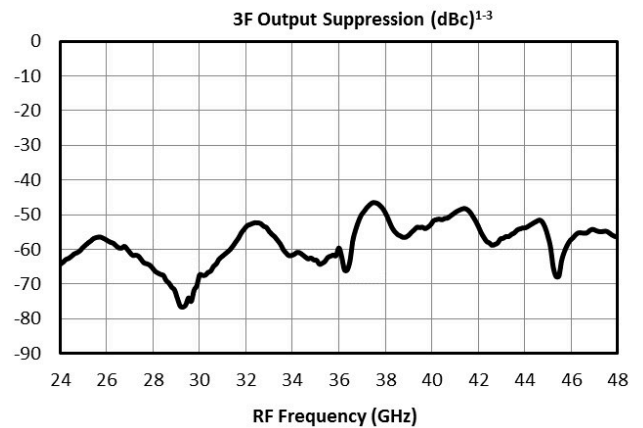
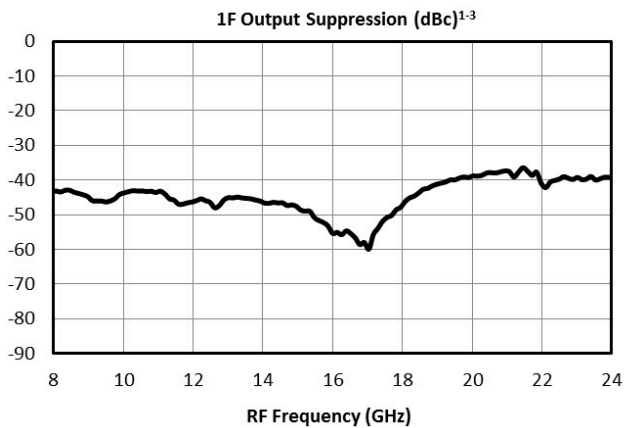
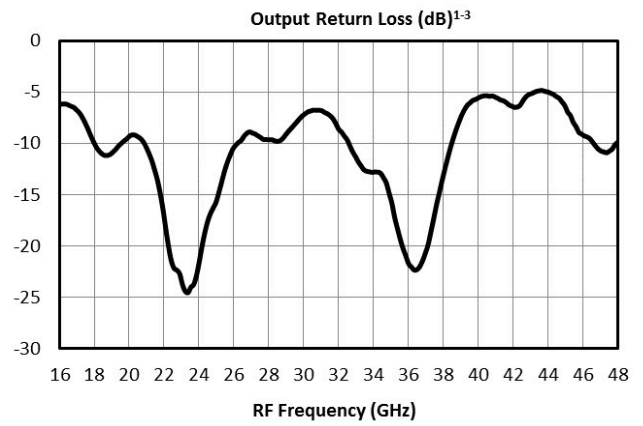
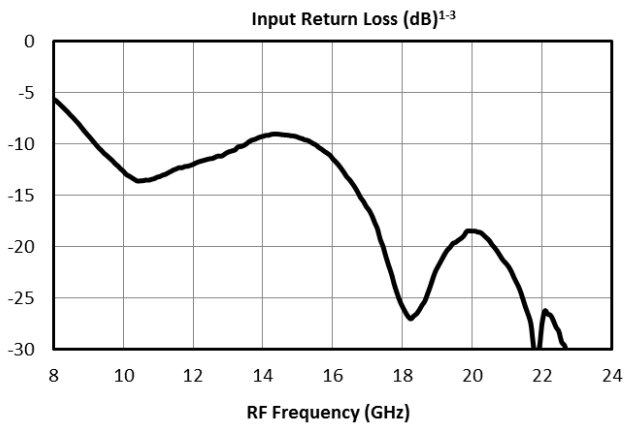
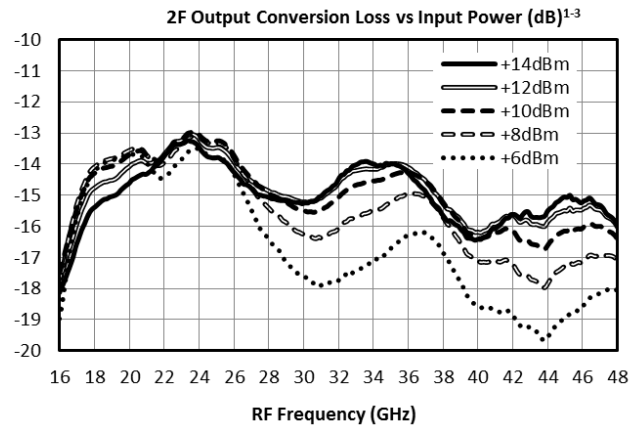
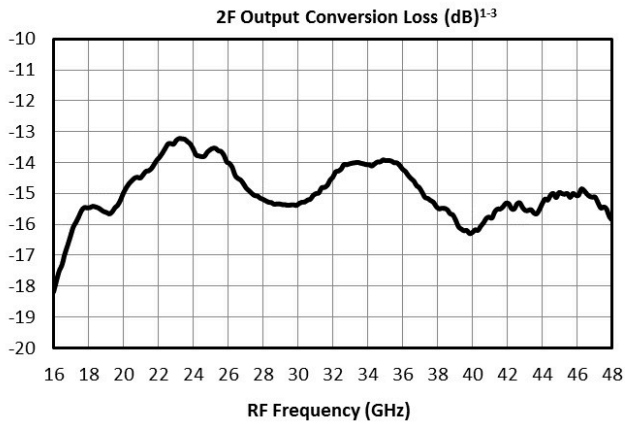
Specifications guaranteed from -55 to +100°C, measured in a 50Ω system. All bare die are 100% DC tested and 100% visually inspected. RF testing is performed on a sample basis to verify conformance to datasheet guaranteed specifications. Consult factory for more information.

Parameter	Test Conditions	Minimum Frequency (GHz)	Maximum Frequency (GHz)	Min	Typ	Max	Unit
5F (out) Fourth Harmonic Suppression ¹	Input = 8 - 24 GHz Output = 16 - 48 GHz Diode Option Input drive level = 10 - 15 dBm	16	48	-	58	-	dBc
Conversion Loss	Second Harmonic Output	16	48	-	15	20	dB
Isolation, 1F ²	Input = 8 - 24 GHz Output = 16 - 48 GHz Diode Option Input drive level = 10 - 15 dBm	8	24	-	59	-	dB
Isolation, 3F ³	Input = 8 - 24 GHz Output = 16 - 48 GHz Diode Option Input drive level = 10 - 15 dBm	16	48	-	85	-	dB
Isolation, 4F ⁴	Input = 8 - 24 GHz Output = 16 - 48 GHz Diode Option Input drive level = 10 - 15 dBm	16	48	-	33	-	dB
Isolation, 5F ⁵	Input = 8 - 24 GHz Output = 16 - 48 GHz Diode Option Input drive level = 10 - 15 dBm	16	48	-	57	-	dB
Suppression, 1F ⁶	Input = 8 - 24 GHz Output = 16 - 48 GHz Diode Option Input drive level = 10 - 15 dBm	8	24	-	44	-	dBc
Suppression, 3F ⁷	Input = 8 - 24 GHz Output = 16 - 48 GHz Diode Option Input drive level = 10 - 15 dBm	16	48	-	69	-	dBc
Suppression, 4F ⁸	Input = 8 - 24 GHz Output = 16 - 48 GHz Diode Option Input drive level = 10 - 15 dBm	16	48	-	33	-	dBc
Input Frequency Range	-	-	-	8	-	24	GHz
Output Frequency Range	-	-	-	16	-	48	GHz

[1][6][7][8] Suppression is relative to 2F doubled output power.

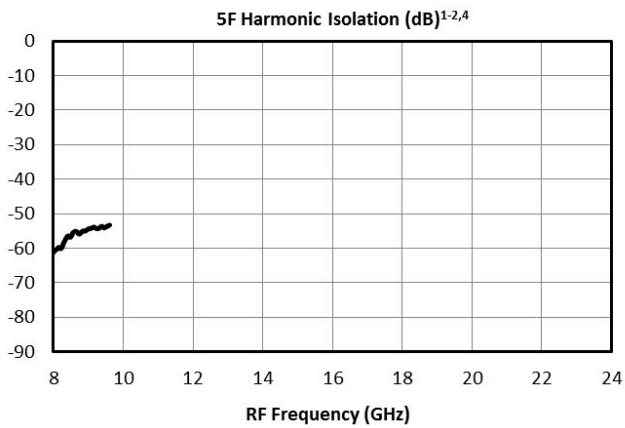
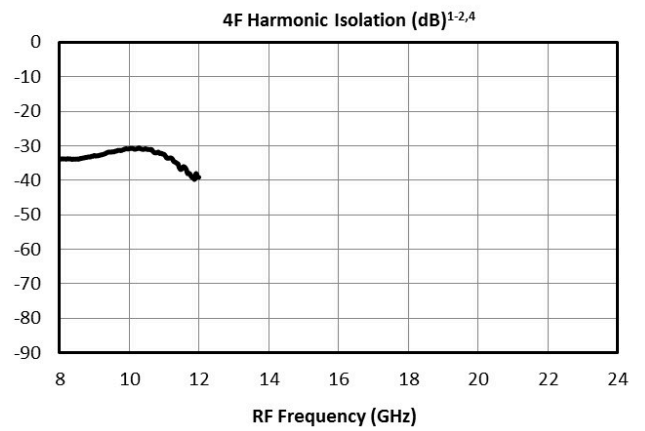
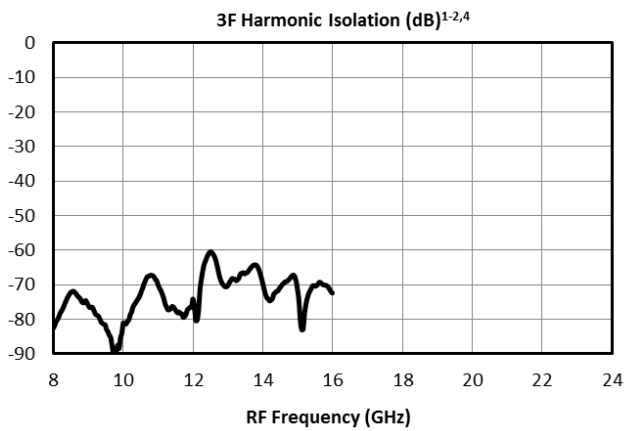
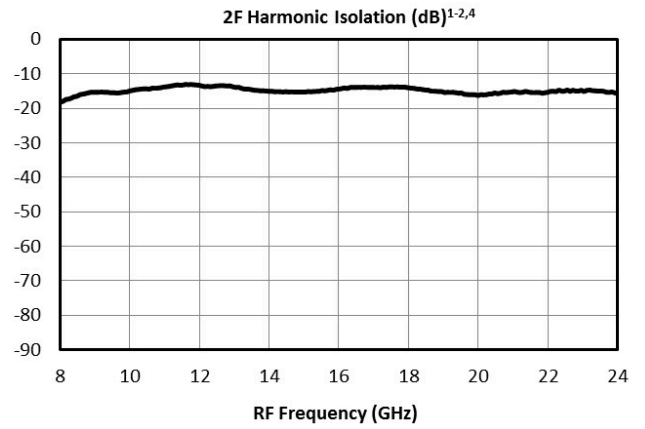
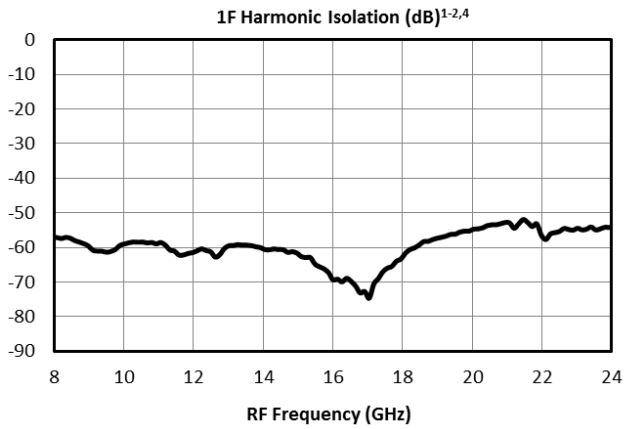
[2][3][4][5] Isolation is defined as relative to the 1F fundamental input power.

Typical Performance Plots



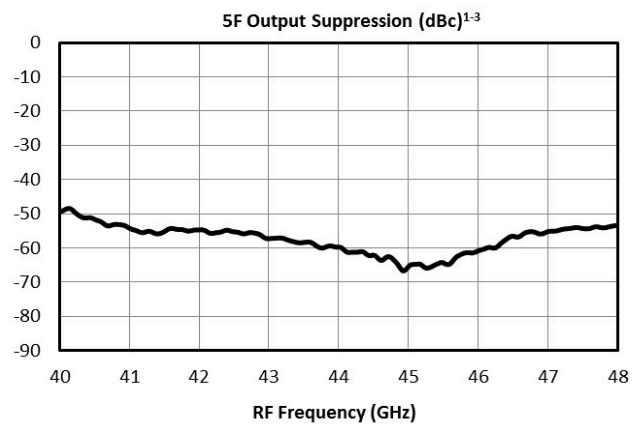
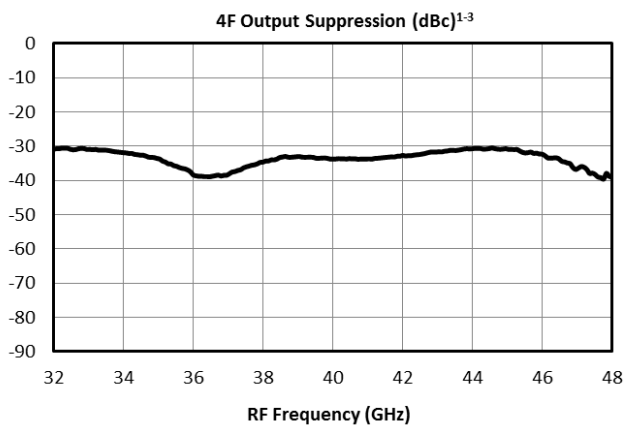
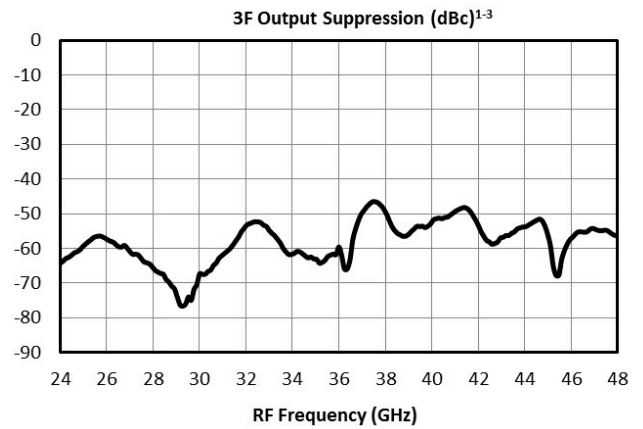
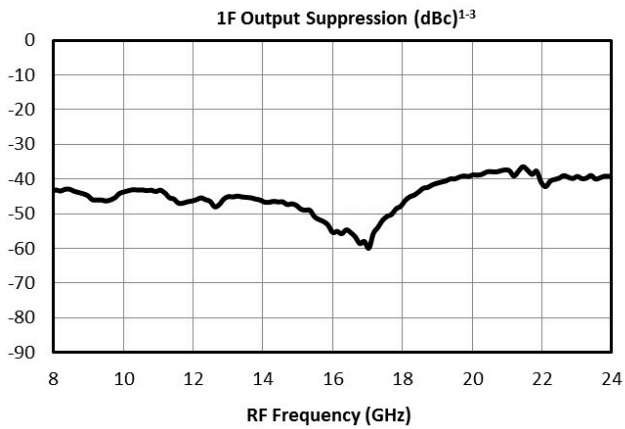
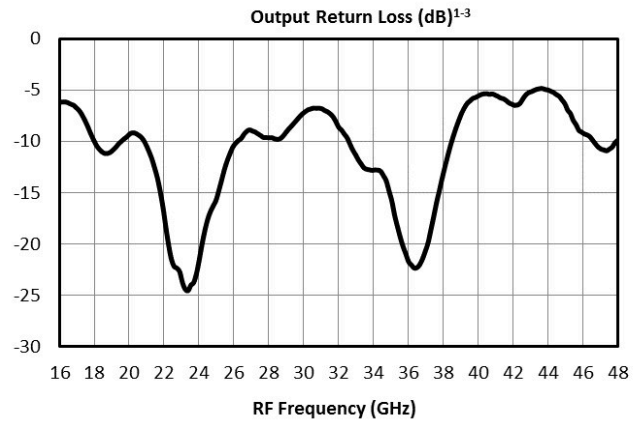
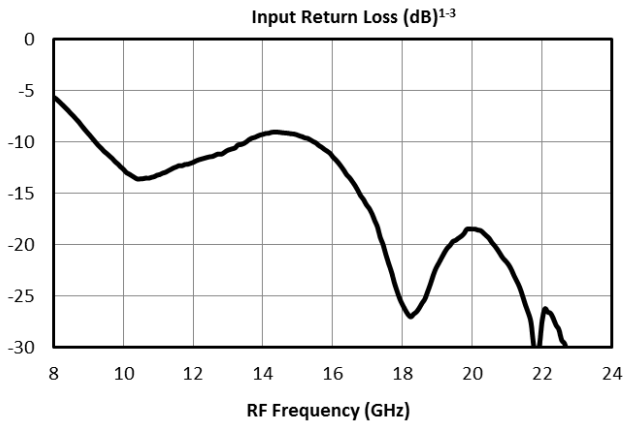
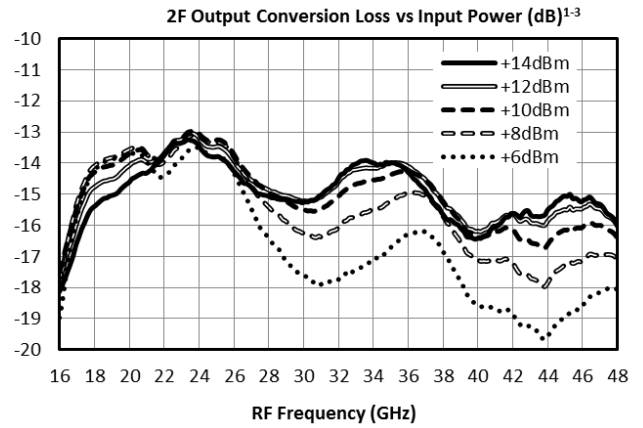
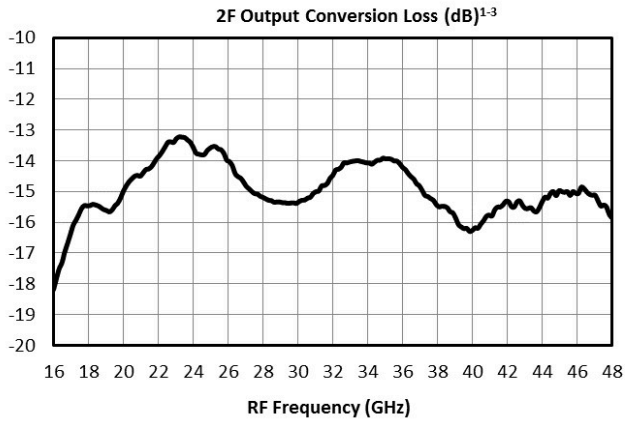
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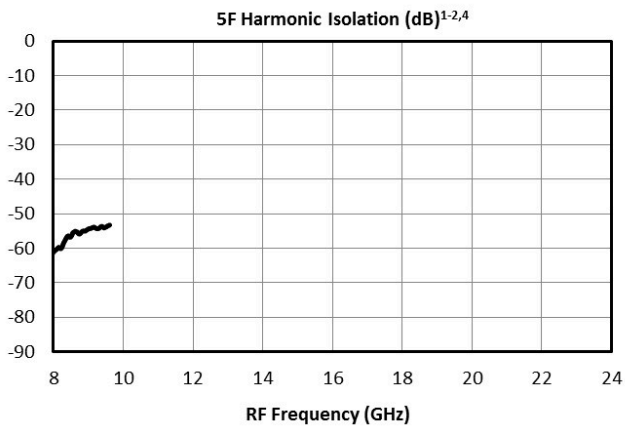
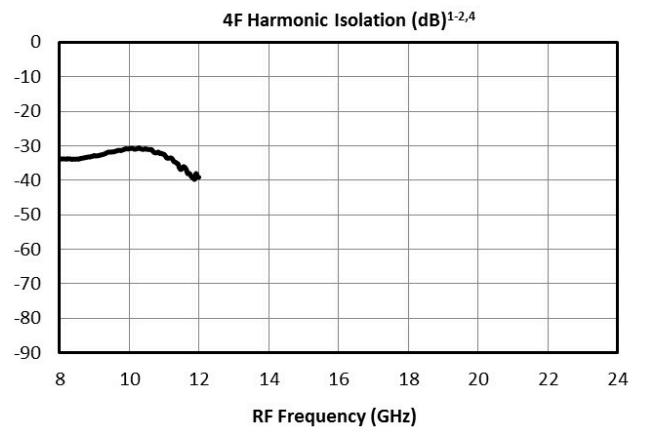
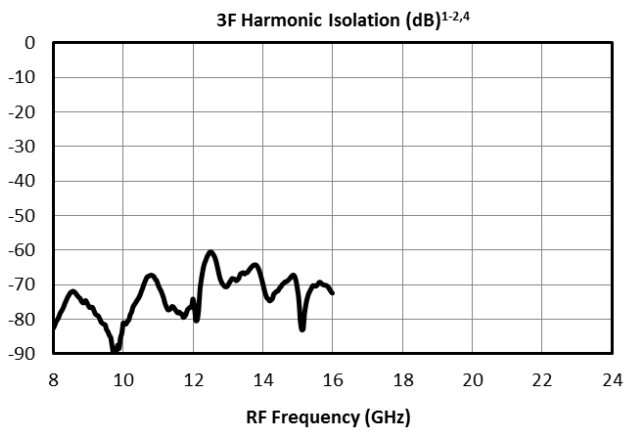
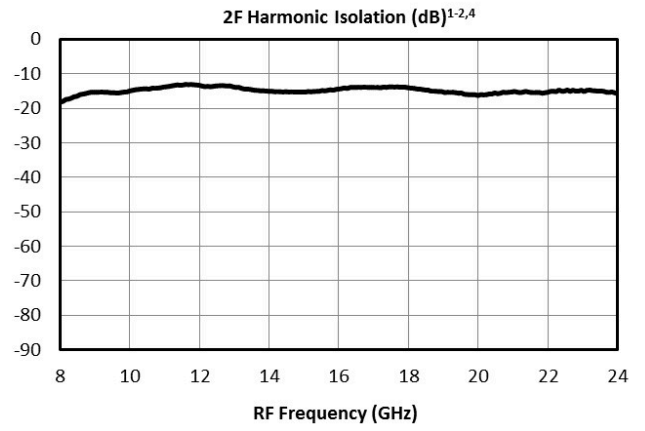
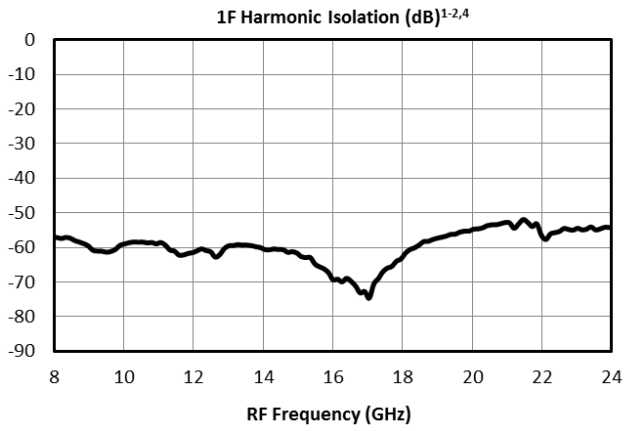
MMD-1648LS - Typical Performance Plots

Performance plots for the connectorized module are shown for measurements where directly probed measurements of the die are unavailable. Note that the following measurements include losses from connectors and microstrip traces.



MMD-1648LCH

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Die Mounting Recommendations

Mounting and Bonding Recommendations

Marki MMICs should be attached directly to a ground plane with conductive epoxy. The ground plane electrical impedance should be as low as practically possible. This will prevent resonances and permit the best possible electrical performance. Datasheet performance is only guaranteed in an environment with a low electrical impedance ground.

Mounting - To epoxy the chip, apply a minimum amount of conductive epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip. Cure epoxy according to manufacturer instructions.

Wire Bonding - Ball or wedge bond with 0.025 mm (1 mil) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 °C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31 mm (12 mils).

Circuit Considerations - 50 Ω transmission lines should be used for all high frequency connections in and out of the chip. Wirebonds should be kept as short as possible, with multiple wirebonds recommended for higher frequency connections to reduce parasitic inductance. In circumstances where the chip more than .001" thinner than the substrate, a heat spreading spacer tab is optional to further reduce bondwire length and parasitic inductance.

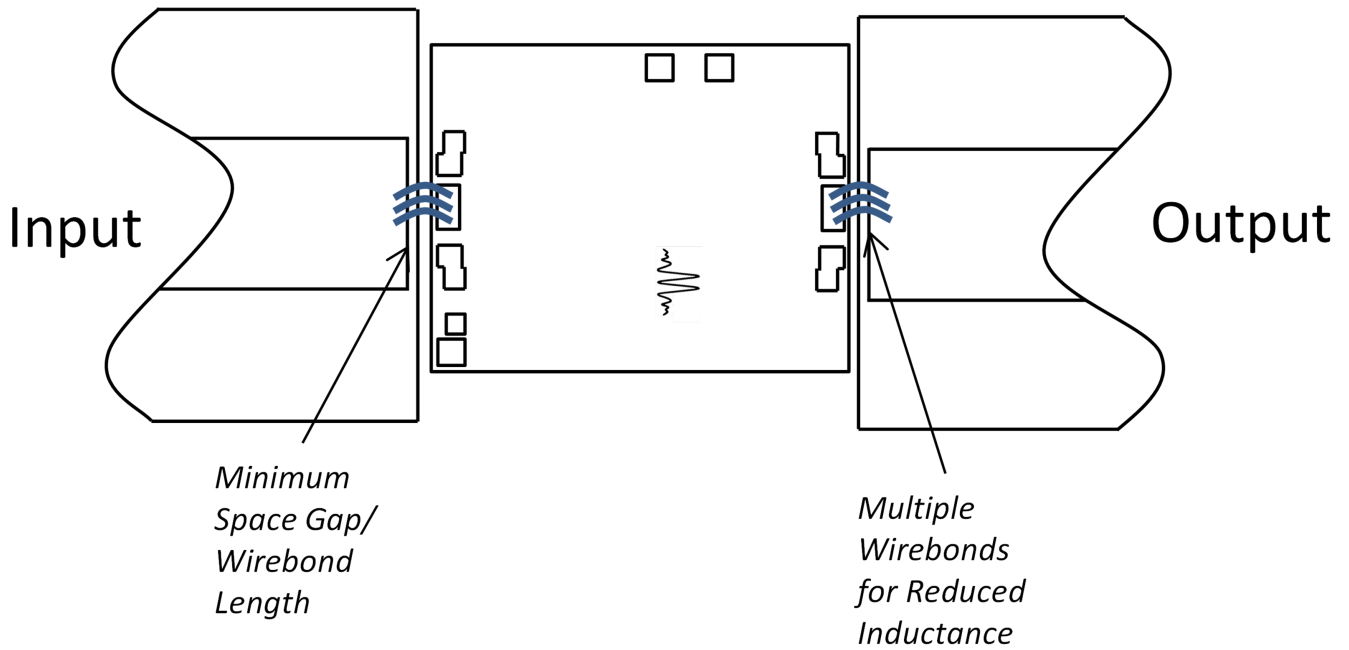
Handling Precautions

General Handling: Chips should be handled with a vacuum collet when possible, or with sharp tweezers using well trained personnel. The surface of the chip is fragile and should not be contacted if possible.

Static Sensitivity: GaAs MMIC devices are subject to static discharge, and should be handled, assembled, tested, and transported only in static protected environments.

Cleaning and Storage: Do not attempt to clean the chip with a liquid cleaning system or expose the bare chips to liquid. Once the ESD sensitive bags the chips are stored in are opened, chips should be stored in a dry nitrogen atmosphere.

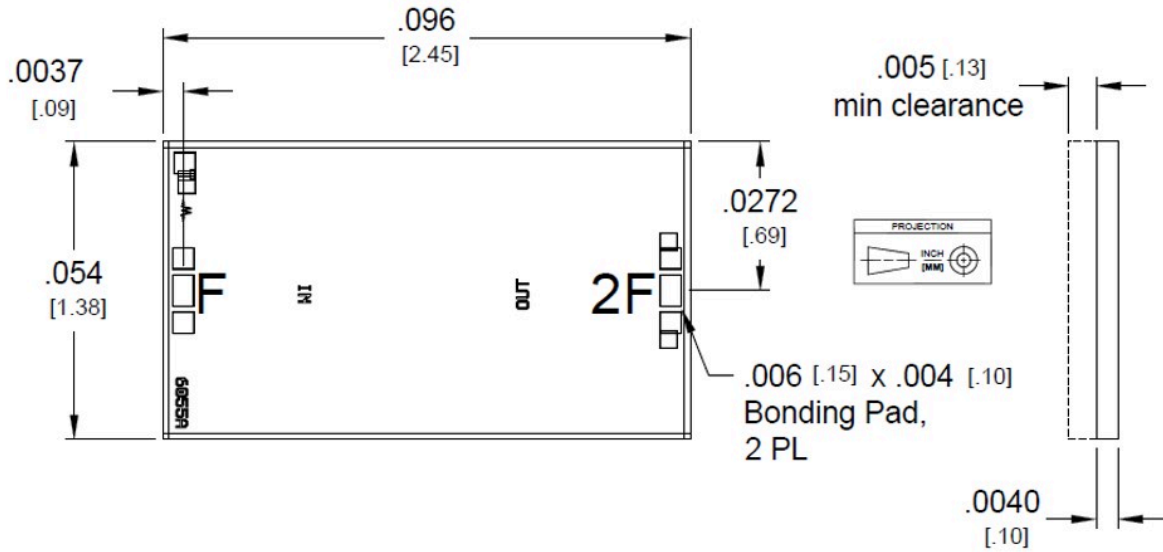
Bonding Diagram



Mechanical Data

Outline Drawing

Download : [Outline 2D Drawing](#)



1. CH Substrate material is .004 thick GaAs.
2. I/O traces and ground plane finish are 2 microns Au.
3. Wire Bonding - Ball or wedge bond with 0.025 mm (1 mil) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 °C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31 mm (12 mils).

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